

初步数据  
Preliminary Data

二极管, 逆变器 / Diode, Inverter  
最大额定值 / Maximum Rated Values

反向重复峰值电压 Repetitive peak reverse voltage	$T_{vj} = 25^{\circ}\text{C}$	$V_{RRM}$	1700	V
连续正向直流电流 Continuous DC forward current		$I_F$	800	A
正向重复峰值电流 Repetitive peak forward current	$t_P = 1 \text{ ms}$	$I_{FRM}$	1600	A
$I^2t$ -值 $I^2t$ - value	$V_R = 0 \text{ V}, t_P = 10 \text{ ms}, T_{vj} = 125^{\circ}\text{C}$	$I^2t$	125	$\text{kA}^2\text{s}$

特征值 / Characteristic Values

			min.	typ.	max.	
正向电压 Forward voltage	$I_F = 800 \text{ A}, V_{GE} = 0 \text{ V}$ $I_F = 800 \text{ A}, V_{GE} = 0 \text{ V}$	$T_{vj} = 25^{\circ}\text{C}$ $T_{vj} = 125^{\circ}\text{C}$	$V_F$	1,80 1,90	2,20	V V
反向恢复峰值电流 Peak reverse recovery current	$I_F = 800 \text{ A}, -di_F/dt = 4900 \text{ A}/\mu\text{s} (T_{vj}=125^{\circ}\text{C})$ $V_R = 900 \text{ V}$ $V_{GE} = -15 \text{ V}$	$T_{vj} = 25^{\circ}\text{C}$ $T_{vj} = 125^{\circ}\text{C}$	$I_{RM}$	780 850		A A
恢复电荷 Recovered charge	$I_F = 800 \text{ A}, -di_F/dt = 4900 \text{ A}/\mu\text{s} (T_{vj}=125^{\circ}\text{C})$ $V_R = 900 \text{ V}$ $V_{GE} = -15 \text{ V}$	$T_{vj} = 25^{\circ}\text{C}$ $T_{vj} = 125^{\circ}\text{C}$	$Q_r$	205 345		$\mu\text{C}$ $\mu\text{C}$
反向恢复损耗 (每脉冲) Reverse recovery energy	$I_F = 800 \text{ A}, -di_F/dt = 4900 \text{ A}/\mu\text{s} (T_{vj}=125^{\circ}\text{C})$ $V_R = 900 \text{ V}$ $V_{GE} = -15 \text{ V}$	$T_{vj} = 25^{\circ}\text{C}$ $T_{vj} = 125^{\circ}\text{C}$	$E_{rec}$	130 225		mJ mJ
结 - 壳热阻 Thermal resistance, junction to case	每个二极管 / per diode		$R_{thJC}$		43,0	K/kW
壳 - 散热器热阻 Thermal resistance, case to heatsink	每个二极管 / per diode $\lambda_{\text{Paste}} = 1 \text{ W}/(\text{m}\cdot\text{K}) / \lambda_{\text{grease}} = 1 \text{ W}/(\text{m}\cdot\text{K})$		$R_{thCH}$	16,0		K/kW

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模块 / Module

绝缘测试电压 Isolation test voltage	RMS, f = 50 Hz, t = 1 min.	V <sub>ISOL</sub>	4,0		kV
模块基板材料 Material of module baseplate			AISiC		
内部绝缘材料 Internal isolation	基本绝缘 (class 1, IEC 61140) basic insulation (class 1, IEC 61140)		AIN		
爬电距离 Creepage distance	如何与取得联系- 散热片 / terminal to heatsink 如何与取得联系- 如何与取得联系 / terminal to terminal		32,2		mm
电气间隙 Clearance	如何与取得联系- 散热片 / terminal to heatsink 如何与取得联系- 如何与取得联系 / terminal to terminal		19,1		mm
相对电痕指数 Comperative tracking index		CTI	> 400		
			min.	typ.	max.
壳 - 散热器热阻 Thermal resistance, case to heatsink	每个模块 / per module $\lambda_{\text{Paste}} = 1 \text{ W/(m}\cdot\text{K)} / \lambda_{\text{grease}} = 1 \text{ W/(m}\cdot\text{K)}$	R <sub>thCH</sub>		8,00	K/kW
杂散电感, 模块 Stray inductance module		L <sub>sCE</sub>		25	nH
模块引线电阻, 端子-芯片 Module lead resistance, terminals - chip	T <sub>C</sub> = 25°C, 每个开关 / per switch	R <sub>AA'+CC'</sub>		0,37	mΩ
最大结温 Maximum junction temperature	逆变器, 制动-斩波器 / inverter, brake-chopper	T <sub>vj max</sub>			150 °C
在开关状态下温度 Temperature under switching conditions	逆变器, 制动-斩波器 / inverter, brake-chopper	T <sub>vj op</sub>	-40		125 °C
储存温度 Storage temperature		T <sub>stg</sub>	-40		125 °C
模块安装的安装扭矩 Mounting torque for modul mounting	螺丝 M6 根据相应的应用手册进行安装 Screw M6 - Mounting according to valid application note	M	4,25	-	5,75 Nm
端子联接扭矩 Terminal connection torque	螺丝 M8 根据相应的应用手册进行安装 Screw M8 - Mounting according to valid application note	M	1,8	-	2,1 Nm
			8,0	-	10 Nm
重量 Weight		G		1050	g

Dynamische Daten gelten in Verbindung mit FF800R17KE3 Modul  
Dynamic data valid in conjunction with FF800R17KE3 module

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